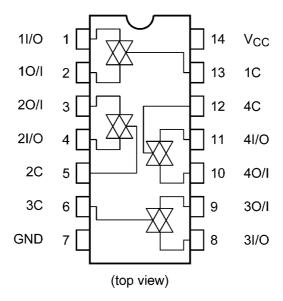
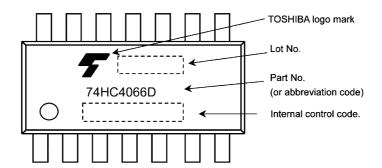


5. Pin Assignment



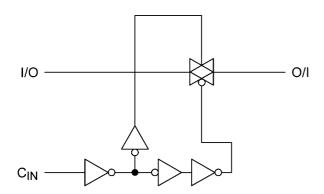
6. Marking



7. Truth Table

Control	Switch Function
Н	On
L	Off

8. System Diagram (per circuit)



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9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 13.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	V
Switch I/O voltage	V _{I/O}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
I/O diode current	I _{I/OK}		±20	mA
Switch through current	Ι _Τ		±25	mA
V _{CC} /ground current	I _{CC}		±50	mA
Power dissipation	P _D	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C.

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		2.0 to 12	V
Input voltage	V _{IN}		0 to V _{CC}	V
Switch I/O voltage	V _{I/O}		0 to V _{CC}	V
Operating temperature	T _{opr}	(Note 1)	-40 to 125	°C
Input rise and fall times	t _r ,t _f		0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_	2.0	1.50	_	_	V
			4.5	3.15	_	_	
			9.0	6.30	_	_	
			12.0	8.40	_	_	
Low-level input voltage	V _{IL}	_	2.0	_		0.50	\ \
			4.5	_	_	1.35	
			9.0	_	_	2.70	
			12.0	_	_	3.60	
ON-resistance	R _{ON}	V _{IN} = V _{IH}	4.5	_	96	170	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1$ mA	9.0	_	55	85	
		1 /0 ≥ 1 IIIA	12.0	_	45	80	
		$\begin{aligned} &V_{IN} = V_{IH} \\ &V_{I/O} = V_{CC} \text{ or GND} \\ &I_{I/O} \leq 1 \text{ mA} \end{aligned}$	2.0	_	160	_	
			4.5	_	70	100	
			9.0	_	50	75	
			12.0	_	45	70	
Difference of ON-resistance	ΔR_{ON}	V _{IN} = V _{IH}	4.5	_	10	30	Ω
between switches		$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1$ mA	9.0	_	5	12	
			12.0	_	5	10	
Input/Output leakage current (Switch OFF)	I _{OFF}	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to V_{CC} $V_{IN} = V_{IL}$	12.0	_		±0.1	μА
Input/Output leakage current (Switch ON, output open)	I _{I/O}	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	12.0	_	_	±0.1	μА
Control input leakage current	I _{IN}	V _{IN} = V _{CC} or GND	12.0	_	_	±0.1	μА
Quiescent supply current	I _{CC}		6.0	_	_	1.0	μА
			9.0	_	_	4.0]
			12.0	_	_	8.0]



11.2. DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_	2.0	1.50	_	V
			4.5	3.15	_	
			9.0	6.30	_	
			12.0	8.40	_	
Low-level input voltage	V _{IL}	_	2.0	_	0.50	V
			4.5	_	1.35]
			9.0	_	2.70	1
			12.0	_	3.60	
ON-resistance	R _{ON}	V _{IN} = V _{IH}	4.5	_	200	Ω
		$\begin{aligned} &V_{I/O} = V_{CC} \text{ to GND} \\ &I_{I/O} \leq 1 \text{ mA} \end{aligned}$ $\begin{aligned} &V_{IN} = V_{IH} \\ &V_{I/O} = V_{CC} \text{ or GND} \\ &I_{I/O} \leq 1 \text{ mA} \end{aligned}$	9.0	_	100	1
			12.0	_	90	
			4.5	_	130	
			9.0	_	95	
			12.0	_	90	
Difference of ON-resistance	ΔR _{ON}	V _{IN} = V _{IH}	4.5	_	35	Ω
between switches		$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1 \text{ mA}$	9.0	_	15	
			12.0	_	12	
Input/Output leakage current (Switch OFF)	I _{OFF}	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to V_{CC} $V_{IN} = V_{IL}$	12.0	_	±1.0	μА
Input/Output leakage current (Switch ON, output open)	I _{I/O}	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	12.0	_	±1.0	μА
Control input leakage current	I _{IN}	V _{IN} = V _{CC} or GND	12.0	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND	6.0		10.0	μΑ
			9.0	_	40.0	
			12.0	_	80.0	



11.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_	2.0	1.50	_	V
			4.5	3.15	_	
			9.0	6.30	_	1
			12.0	8.40	_	
Low-level input voltage	V _{IL}	_	2.0	_	0.50	V
			4.5	_	1.35	
			9.0	_	2.70	
			12.0	_	3.60	
ON-resistance	R _{ON}	V _{IN} = V _{IH}	4.5	_	220	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1 \text{ mA}$	9.0	_	110	
		11/0 = 11117	12.0	_	100	
		$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ or GND $I_{I/O} \le 1$ mA	4.5	_	150	
			9.0	_	110	
			12.0	_	105	
Difference of ON-resistance	ΔR_{ON}	V _{IN} = V _{IH}	4.5	_	35	Ω
between switches		$V_{I/O} = V_{CC}$ to GND $I_{I/O} \le 1 \text{ mA}$	9.0	_	15	
		11/0 = 11117	12.0	_	12	
Input/Output leakage current (Switch OFF)	I _{OFF}	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to V_{CC} $V_{IN} = V_{IL}$	12.0	_	±5.0	μА
Input/Output leakage current (Switch ON, output open)	I _{I/O}	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	12.0	_	±5.0	μА
Control input leakage current	I _{IN}	V _{IN} = V _{CC} or GND	12.0	_	±5.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND	6.0	_	20.0	μА
			9.0	_	80.0]
			12.0		160.0]

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11.4. AC Characteristics (Unless otherwise specified, $C_L = 50$ pF, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit	
Phase difference between	Φι/Ο		_	2.0	_	10	50	ns	
input to output				4.5	_	4	10		
				9.0	_	3	8		
				12.0	_	3	7		
Output enable time	t _{PZL} ,		$R_L = 1 \text{ k}\Omega$	2.0	_	18	100	ns	
	t _{PZH}		See 12. AC Test Circuit, Figure 1	4.5	_	8	20		
			i iguie i	9.0	_	6	12		
				12.0	_	6	12		
Output disable time	t _{PLZ} ,	F		R _L = 1 kΩ	2.0	_	20	115	ns
	t _{PHZ}		See 12. AC Test Circuit, Figure 1	4.5	_	10	23		
			i iguie i	9.0	_	8	20		
				12.0	_	8	12		
Control input capacitance	C _{IN}		_	5.0	_	3	10	pF	
Switch terminal capacitance	Cos		See 12. AC Test Circuit, Figure 2	5.0	_	6	20	pF	
Feedthrough capacitance	C _{IOS}		See 12. AC Test Circuit, Figure 2	5.0	_	0.5	2	pF	
Power dissipation capacitance	C _{PD}	(Note 1)	See 12. AC Test Circuit, Figure 2	5.0		5	_	pF	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/4 \text{ (per bit)}$

11.5. AC Characteristics (Unless otherwise specified, $C_L = 50$ pF, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit				
Phase difference between input to	Ψι/Ο	_	2.0	_	65	ns				
output			4.5	_	13					
			9.0	_	10					
			12.0	_	9					
Output enable time	t_{PZL}, t_{PZH}	$R_L = 1 k\Omega$	2.0	_	125	ns				
						See 12. AC Test Circuit, Figure 1	4.5	_	25	
			9.0	_	22					
			12.0	_	18					
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 \text{ k}\Omega$	2.0	_	145	ns				
		See 12. AC Test Circuit, Figure 1	4.5	_	29					
			9.0	_	25					
			12.0	_	22					
Control input capacitance	C _{IN}		5.0		10	pF				
Switch terminal capacitance	Cos	See 12. AC Test Circuit, Figure 2	5.0	_	20	pF				
Feedthrough capacitance	C _{IOS}	See 12. AC Test Circuit, Figure 2	5.0	_	2	pF				



11.6. AC Characteristics (Note) (Unless otherwise specified, $C_L = 50$ pF, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Phase difference between input to	Ψι/Ο	_	2.0	_	75	ns
output			4.5	_	15	
			9.0	_	12	
			12.0	_	11	
Output enable time	t _{PZL} ,t _{PZH}	$R_L = 1 k\Omega$	2.0	_	145	ns
		See 12. AC Test Circuit, Figure 1	4.5	_	29	
			9.0	_	29	
			12.0	_	22	
Output disable time	t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	2.0	_	165	ns
		See 12. AC Test Circuit, Figure 1	4.5	_	33	
			9.0	_	29	
			12.0	_	29	
Control input capacitance	C _{IN}	_	5.0	_	10	pF
Switch terminal capacitance	Cos	See 12. AC Test Circuit, Figure 2	5.0	_	20	pF
Feedthrough capacitance	C _{IOS}	See 12. AC Test Circuit, Figure 2	5.0	_	2	pF

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

11.7. Analog Switch Characteristics (T_a = 25 °C) (Note)

Characteristics	Symbol	Test Condition	Test Condition		Тур.	Unit
Sine Wave Distortion	THD	$R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$, $f_{IN} = 1 \text{ kHz}$	$V_{IN} = 4.5 V_{p-p}$	4.5	0.05	%
			$V_{IN} = 9.0 V_{p-p}$	9.0	0.04	
Maximum frequency response (switch ON)	f _{MAX(I/O)}	V _{IN} is centered at (V _{CC} /2). Adjust input for 0dBm. Increase f _{IN} frequency until dB meter		4.5	200	MHz
		reads -3dB. R_L = 50 Ω , C_L = 10 pF, f_{IN} = 1 MHz, sine wave See 12. AC Test Circuit, Figure 3		9.0	200	
Feed through attenuation (switch OFF)	FTH	V _{IN} is centered at (V _{CC} /2). Adjust input for 0dBm.		4.5	-60	dB
		R_L = 600 Ω , C_L = 50 pF, f_{IN} = 1 MHz, sine wave See 12. AC Test Circuit, Figure 4		9.0	-60	
Crosstalk (control input to signal output)	X _{talk}	$R_L = 600 \Omega$, $C_L = 50 pF$, $f_{IN} = 1 MHz$,		4.5	60	mV
		square wave (t _r = t _f = 6 ns) See 12. AC Test Circuit, Figure 5		9.0	100	
Crosstalk (between any switches)	X _{talk}	V _{IN} is centered at (V _{CC} /2). Adjust input for 0dBm.		4.5	-60	dB
		R_L = 600 Ω , C_L = 50 pF, f_{IN} = 1 MHz, sine wave See 12. AC Test Circuit, Figure 6		9.0	-60	

Note: These characteristics are determined by design of devices.



12. AC Test Circuit

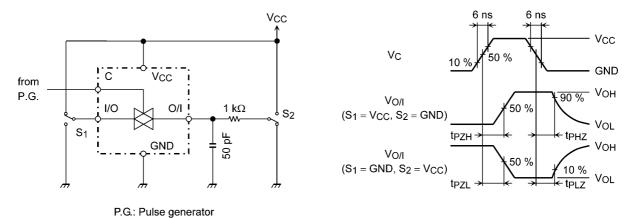


Figure 1 tpLZ, tpHZ, tpZL, tpZH

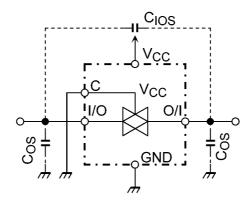


Figure 2 C_{IOS}, C_{OS}

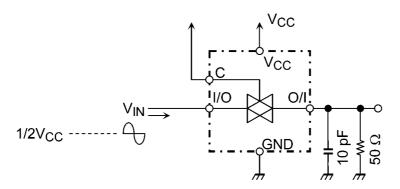


Figure 3 Frequency Response (switch on)

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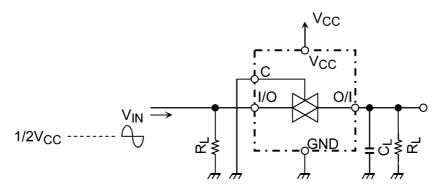


Figure 4 Feedthrough

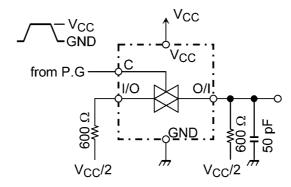


Figure 5 Cross Talk (control input to output signal)

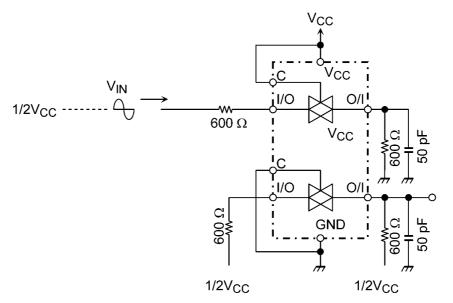
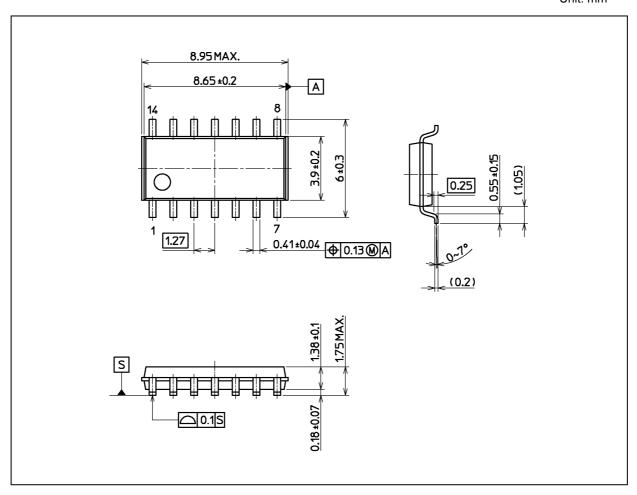


Figure 6 Cross Talk (between any two switches)



Package Dimensions

Unit: mm



Weight: 0.13 g (typ.)

	Package Name(s)
Nickname: SOIC14	



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